

2W Filter-free Class D Audio Power Amplifier

PRELIMINARY DATA

- Operating from $V_{CC}=2.5V$ to $5.5V$
- Standby mode active low
- Output power: $1.2W @ 5V$ or $0.45W @ 3.0V$ into 8Ω with 1% THD max.
- Adjustable gain via external resistors
- Low current consumption 2mA
- Efficiency: 87% typ.
- Signal to noise ratio: 85dB typ.
- PSRR: 63dB typ. with 6dB gain
- PWM base frequency: 250kHz
- Low pop & click noise
- Thermal shutdown protection
- Available in flip-chip 9 x 300um

Description

The TS4962 is a differential class-D B.T.L. power amplifier. Able to drive up to 1.2W into a 8Ω load at 5V, it achieves outstanding efficiency (87% typ.) compared to classical AB-class audio amps.

Gain of the device can be controlled via two external gain setting resistors.

A POP & CLICK reduction circuitry provides low on/off switch noise while allowing the device to start within 5ms.

A standby function (active low) allows to lower the current consumption to 10nA typ.

The TS4962 is available in a flip-chip package of 9 bumps of 300um diameter.

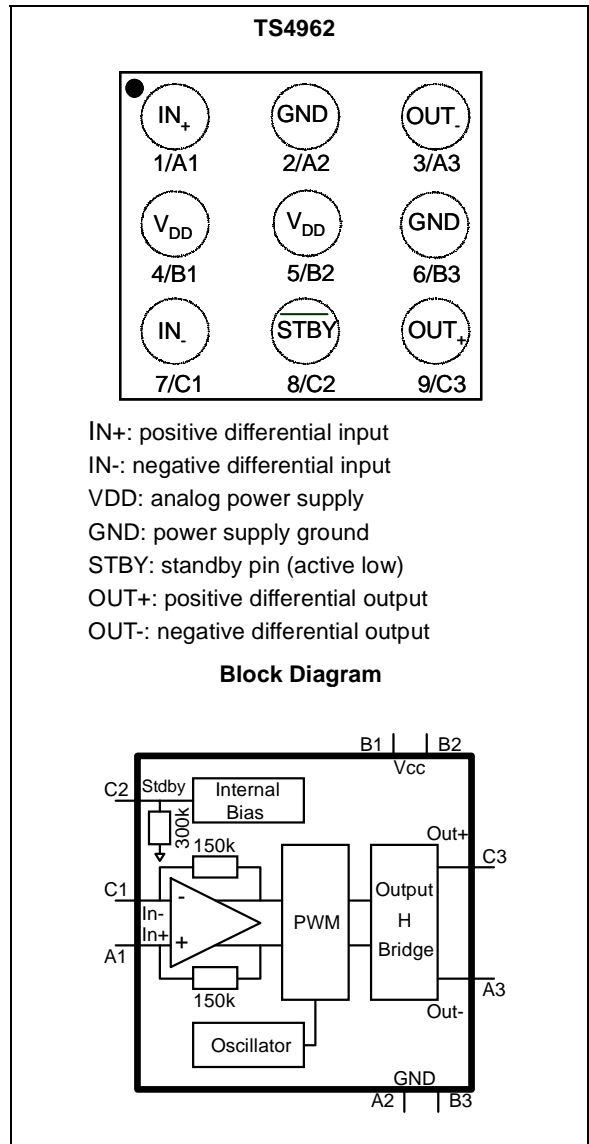
Applications

- Cellular Phone
- PDA
- Notebook PC

Order Code

Part Number	Temperature Range	Package	Packaging	Marking
TS4962IJT	-40, +85°C	Flip-Chip	Tape & Reel	A62
TS4962EIJT	-40, +85°C	Lead -Free Flip-Chip	Tape & Reel	A62
TS4962EKIJT	-40, +85°C	Lead Free + Back Coating	Tape & Reel	A62

Pin Connections (top view)



- IN+: positive differential input
- IN-: negative differential input
- VDD: analog power supply
- GND: power supply ground
- STBY: standby pin (active low)
- OUT+: positive differential output
- OUT-: negative differential output

1 Absolute Maximum Ratings

Table 1: Key parameters and their absolute maximum ratings

Symbol	Parameter	Value	Unit
VCC	Supply voltage ¹	6	V
V _i	Input Voltage ²	G _{ND} to V _{CC}	V
T _{oper}	Operating Free Air Temperature Range	-40 to + 85	°C
T _{stg}	Storage Temperature	-65 to +150	°C
T _j	Maximum Junction Temperature	150	°C
R _{thja}	Thermal Resistance Junction to Ambient ³	200	°C/W
P _d	Power Dissipation	Internally Limited ⁴	
ESD	Human Body Model	tbd	kV
ESD	Machine Model	tbd	V
Latch-up	Latch-up Immunity	tbd	mA
V _{STB}	Standby pin voltage maximum voltage ⁵	G _{ND} to V _{CC}	V
	Lead Temperature (soldering, 10sec)	260	°C

- 1) All voltages values are measured with respect to the ground pin.
- 2) The magnitude of input signal must never exceed V_{CC} + 0.3V / G_{ND} - 0.3V
- 3) Device is protected in case of over temperature by a thermal shutdown active @ 150°C.
- 4) Exceeding the power derating curves during a long period, involves abnormal operating condition.
- 5) The magnitude of standby signal must never exceed V_{CC} + 0.3V / G_{ND} - 0.3V

Table 2: Operating Conditions

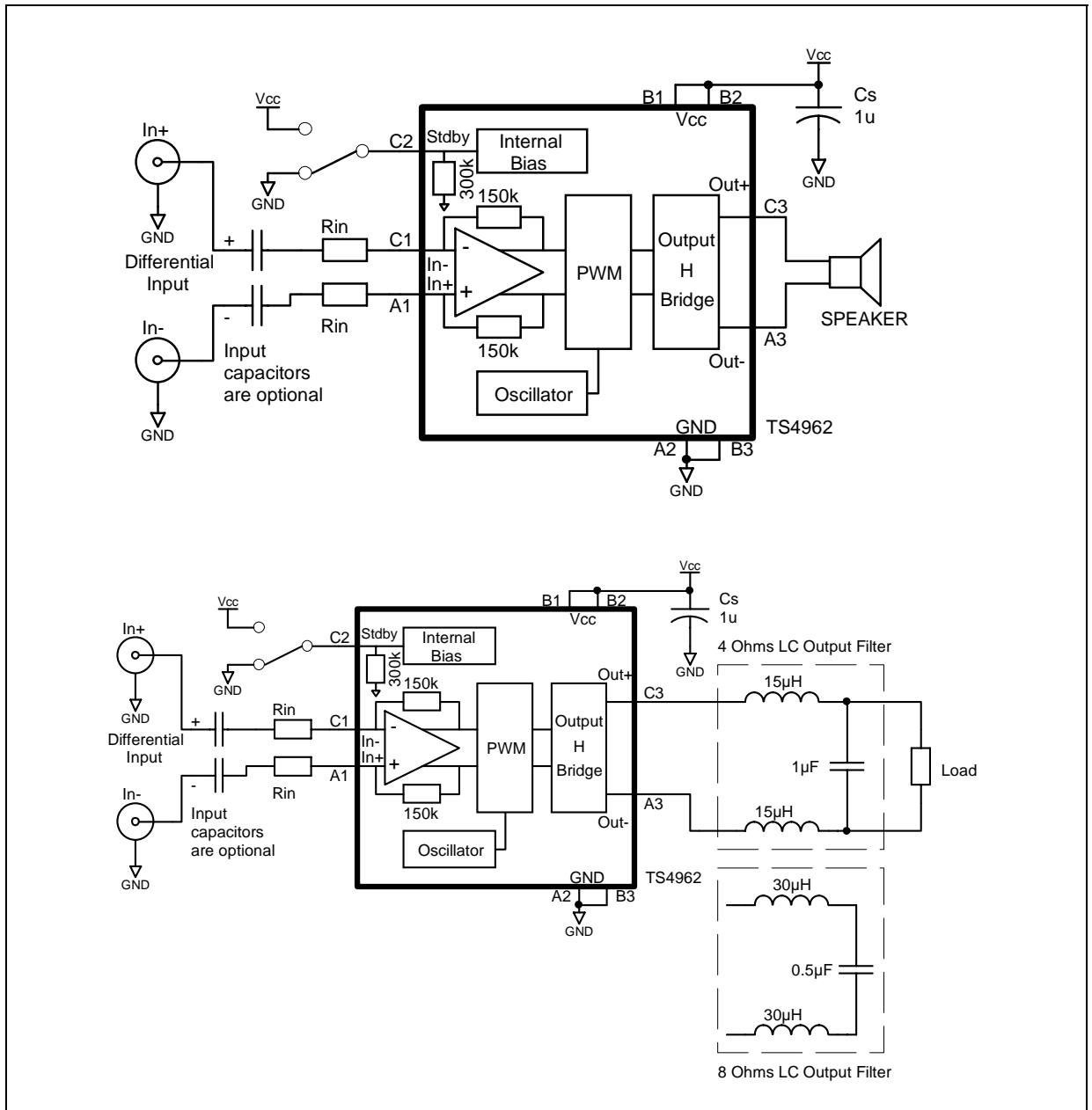
Symbol	Parameter	Value	Unit
VCC	Supply Voltage	2.5 to 5.5	V
V _{IC}	Common Mode Input Voltage Range	0.5 to V _{CC} -0.8	V
V _{STB}	Standby Voltage Input : ¹ Device ON Device OFF	$1.4 \leq V_{STB} \leq V_{CC}$ $G_{ND} \leq V_{STB} \leq 0.4$ ²	V
RL	Load Resistor	≥ 4	Ω
R _{thja}	Thermal Resistance Junction to Ambient ³	90	°C/W

- 1) Without any signal on V_{STB}, the device will be in standby
- 2) Minimum current consumption shall be obtained when V_{STB} = G_{ND}.
- 3) With heat sink surface = 125mm².

2 Application Components Information

Components	Functional Description
Cs	Bypass supply capacitor. To install as close as possible of the TS4962 to minimize high frequency ripple. A 100nF ceramic capacitor should be add to enhance the power supply filtering in high frequency.
Rin	Input resistor to program the TS4962 gain (Gain = 300/Rin with rin in kΩ)
Input Capacitor	Thanks to common mode feedback, these input capacitors are optional. However, we can add them to form with Rin a 1st order high pass filter with -3dB cut-off frequency = $1/(2 \cdot \pi \cdot R_{in} \cdot C_{in})$

Figure 1: Typical application



3 Electrical Characteristics

Table 3: $V_{CC} = +5V$, $GND = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
I_{CC}	Supply Current No input signal, no load		2.3		mA
$I_{STANDBY}$	Standby Current ¹ No input signal, $V_{STBY} = GND$		10	1000	nA
V_{OO}	Output Offset Voltage No input signal, $R_L = 8\Omega$		3		mV
P_o	Output Power, $G=6dB$ THD = 2% Max, $f = 1kHz$, $R_L = 4\Omega$ THD = 1% Max, $f = 1kHz$, $R_L = 8\Omega$		2 1.2		W
THD + N	Total Harmonic Distortion + Noise $P_o = 900\text{ mW}_{RMS}$, $G = 6dB$, $20Hz < f < 20kHz$, $R_L = 8\Omega + 15\mu H$, $BW < 30kHz$		1		%
Efficiency	Efficiency $P_o = 2\text{ W}_{RMS}$, $R_L = 4\Omega + \geq 15\mu H$ $P_o = 1.2\text{ W}_{RMS}$, $R_L = 8\Omega + \geq 15\mu H$		77 87		%
PSRR	Power Supply Rejection Ratio with inputs grounded ² $f = 217Hz$, $R_L = 8\Omega$, $G=6dB$, $V_{ripple} = 200mV_{pp}$		63		dB
CMRR	Common Mode Rejection Ratio, $f = 217Hz$, $R_L = 8\Omega$, $G = 6dB$, $\Delta V_{ic} = 200mV_{pp}$		57		dB
Gain	Gain value (R_{in} in $k\Omega$)	$\frac{240\text{ k}\Omega}{R_{in}}$	$\frac{300\text{ k}\Omega}{R_{in}}$	$\frac{360\text{ k}\Omega}{R_{in}}$	dB
R_{STDBY}	Internal Resistance From Standby to GND	240	300	360	$k\Omega$
F_{PWM}	Pulse Width Modulator Base Frequency		250		kHz
SNR	Signal to Noise ratio (A Weighting), $P_o = 1.2W$, $R_L = 8\Omega$		85		dB
T_{WU}	Wake-up time		5		ms
T_{STB}	Standby time		5		ms
V_N	Output Voltage Noise $f = 20Hz$ to $20kHz$, $G = 6dB$ Unweighted $R_L = 4\Omega$ A weighted $R_L = 4\Omega$ Unweighted $R_L = 8\Omega$ A weighted $R_L = 8\Omega$ Unweighted $R_L = 4\Omega + 15\mu H$ A weighted $R_L = 4\Omega + 15\mu H$ Unweighted $R_L = 4\Omega + 30\mu H$ A weighted $R_L = 4\Omega + 30\mu H$ Unweighted $R_L = 8\Omega + 30\mu H$ A weighted $R_L = 8\Omega + 30\mu H$ Unweighted $R_L = 4\Omega + \text{Filter}$ A weighted $R_L = 4\Omega + \text{Filter}$ Unweighted $R_L = 4\Omega + \text{Filter}$ A weighted $R_L = 4\Omega + \text{Filter}$		85 60 86 62 83 60 88 64 78 57 87 65 82 59 90 66		μV_{RMS}

1) Standby mode is activated when V_{stdby} is tied to GND.

2) Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. V_{ripple} is the surimposed sinus signal to V_{cc} @ $f = 217Hz$.

Table 4: $V_{CC} = +4.2V$, $GND = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified) ¹

Symbol	Parameter	Min.	Typ.	Max.	Unit	
I_{CC}	Supply Current No input signal, no load		2.1		mA	
$I_{STANDBY}$	Standby Current ² No input signal, $V_{STBY} = GND$		10	1000	nA	
V_{OO}	Output Offset Voltage No input signal, $R_L = 8\Omega$		3		mV	
P_o	Output Power, $G=6dB$ THD = 2% Max, $f = 1kHz$, $R_L = 4\Omega$ THD = 1% Max, $f = 1kHz$, $R_L = 8\Omega$		1.5 0.9		W	
THD + N	Total Harmonic Distortion + Noise $P_o = 600 mW_{RMS}$, $G = 6dB$, $20Hz < f < 20kHz$, $R_L = 8\Omega + 15\mu H$, $BW < 30kHz$		1		%	
Efficiency	Efficiency $P_o = 1.5 W_{RMS}$, $R_L = 4\Omega + \geq 15\mu H$ $P_o = 0.9 W_{RMS}$, $R_L = 8\Omega + \geq 15\mu H$		78 87		%	
PSRR	Power Supply Rejection Ratio with inputs grounded ³ $f = 217Hz$, $R_L = 8\Omega$, $G=6dB$, $V_{ripple} = 200mV_{pp}$		63		dB	
CMRR	Common Mode Rejection Ratio, $f = 217Hz$, $R_L = 8\Omega$, $G = 6dB$, $\Delta V_{ic} = 200mV_{pp}$		57		dB	
Gain	Gain value (R_{in} in $k\Omega$)		$\frac{240 k\Omega}{R_{in}}$	$\frac{300 k\Omega}{R_{in}}$	$\frac{360 k\Omega}{R_{in}}$	V/V
R_{STDBY}	Internal Resistance From Standby to GND	240	300	360	$k\Omega$	
F_{PWM}	Pulse Width Modulator Base Frequency		250		kHz	
SNR	Signal to Noise ratio (A Weighting), $P_o = 0.9W$, $R_L = 8\Omega$		85		dB	
T_{WU}	Wake-up time		5		ms	
T_{STB}	Standby time		5		ms	
V_N	Output Voltage Noise $f = 20Hz$ to $20kHz$, $G = 6dB$ Unweighted $R_L = 4\Omega$ A weighted $R_L = 4\Omega$ Unweighted $R_L = 8\Omega$ A weighted $R_L = 8\Omega$ Unweighted $R_L = 4\Omega + 15\mu H$ A weighted $R_L = 4\Omega + 15\mu H$ Unweighted $R_L = 4\Omega + 30\mu H$ A weighted $R_L = 4\Omega + 30\mu H$ Unweighted $R_L = 8\Omega + 30\mu H$ A weighted $R_L = 8\Omega + 30\mu H$ Unweighted $R_L = 4\Omega + Filter$ A weighted $R_L = 4\Omega + Filter$ Unweighted $R_L = 4\Omega + Filter$ A weighted $R_L = 4\Omega + Filter$		85 60 86 62 83 60 88 64 78 57 87 65 82 59 90 66		μV_{RMS}	

1) All electrical values are guaranteed with correlation measurements at 2.5V and 5V.

2) Standby mode is activated when V_{stdby} is tied to GND.

3) Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. V_{ripple} is the surimposed sinus signal to V_{cc} @ $f = 217Hz$.

Table 5: $V_{CC} = +3.6V$, $GND = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified) ¹

Symbol	Parameter	Min.	Typ.	Max.	Unit
I_{CC}	Supply Current No input signal, no load		2		mA
$I_{STANDBY}$	Standby Current ² No input signal, $V_{STBY} = GND$		10	1000	nA
V_{OO}	Output Offset Voltage No input signal, $R_L = 8\Omega$		3		mV
P_o	Output Power, $G=6dB$ THD = 2% Max, $f = 1kHz$, $R_L = 4\Omega$ THD = 1% Max, $f = 1kHz$, $R_L = 8\Omega$		1 0.6		W
THD + N	Total Harmonic Distortion + Noise $P_o = 500 mW_{RMS}$, $G = 6dB$, $20Hz < f < 20kHz$, $R_L = 8\Omega + 15\mu H$, $BW < 30kHz$		1		%
Efficiency	Efficiency $P_o = 1 W_{RMS}$, $R_L = 4\Omega + \geq 15\mu H$ $P_o = 0.6 W_{RMS}$, $R_L = 8\Omega + \geq 15\mu H$		78 87		%
PSRR	Power Supply Rejection Ratio with inputs grounded ³ $f = 217Hz$, $R_L = 8\Omega$, $G=6dB$, $V_{ripple} = 200mV_{pp}$		62		dB
CMRR	Common Mode Rejection Ratio, $f = 217Hz$, $R_L = 8\Omega$, $G = 6dB$, $\Delta V_{ic} = 200mV_{pp}$		56		dB
Gain	Gain value (R_{in} in $k\Omega$)	$\frac{240 k\Omega}{R_{in}}$	$\frac{300 k\Omega}{R_{in}}$	$\frac{360 k\Omega}{R_{in}}$	V/V
R_{STDBY}	Internal Resistance From Standby to GND	240	300	360	$k\Omega$
F_{PWM}	Pulse Width Modulator Base Frequency		250		kHz
SNR	Signal to Noise ratio (A Weighting), $P_o = 0.6W$, $R_L = 8\Omega$		83		dB
T_{WU}	Wake-up time		5		ms
T_{STB}	Standby time		5		ms
V_N	Output Voltage Noise $f = 20Hz$ to $20kHz$, $G = 6dB$ Unweighted $R_L = 4\Omega$ A weighted $R_L = 4\Omega$ Unweighted $R_L = 8\Omega$ A weighted $R_L = 8\Omega$ Unweighted $R_L = 4\Omega + 15\mu H$ A weighted $R_L = 4\Omega + 15\mu H$ Unweighted $R_L = 4\Omega + 30\mu H$ A weighted $R_L = 4\Omega + 30\mu H$ Unweighted $R_L = 8\Omega + 30\mu H$ A weighted $R_L = 8\Omega + 30\mu H$ Unweighted $R_L = 4\Omega + Filter$ A weighted $R_L = 4\Omega + Filter$ Unweighted $R_L = 4\Omega + Filter$ A weighted $R_L = 4\Omega + Filter$		83 57 83 61 81 58 87 62 77 56 85 63 80 57 85 61		μV_{RMS}

1) All electrical values are guaranteed with correlation measurements at 2.5V and 5V.

2) Standby mode is activated when V_{stdby} is tied to GND.

3) Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. V_{ripple} is the surimposed sinus signal to V_{cc} @ $f = 217Hz$.

Table 6: $V_{CC} = +3.0V$, $GND = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified) ¹

Symbol	Parameter	Min.	Typ.	Max.	Unit
I_{CC}	Supply Current No input signal, no load		1.9		mA
$I_{STANDBY}$	Standby Current ² No input signal, $V_{STBY} = GND$		10	1000	nA
V_{OO}	Output Offset Voltage No input signal, $R_L = 8\Omega$		3		mV
P_o	Output Power, $G=6dB$ THD = 2% Max, $f = 1kHz$, $R_L = 4\Omega$ THD = 1% Max, $f = 1kHz$, $R_L = 8\Omega$		0.7 0.4		W
THD + N	Total Harmonic Distortion + Noise $P_o = 500 mW_{RMS}$, $G = 6dB$, $20Hz < f < 20kHz$, $R_L = 8\Omega + 15\mu H$, $BW < 30kHz$		1		%
Efficiency	Efficiency $P_o = 0.7 W_{RMS}$, $R_L = 4\Omega + \geq 15\mu H$ $P_o = 0.4 W_{RMS}$, $R_L = 8\Omega + \geq 15\mu H$		78 87		%
PSRR	Power Supply Rejection Ratio with inputs grounded ³ $f = 217Hz$, $R_L = 8\Omega$, $G=6dB$, $V_{ripple} = 200mV_{pp}$		60		dB
CMRR	Common Mode Rejection Ratio, $f = 217Hz$, $R_L = 8\Omega$, $G = 6dB$, $\Delta V_{ic} = 200mV_{pp}$		54		dB
Gain	Gain value (R_{in} in $k\Omega$)	$\frac{240 k\Omega}{R_{in}}$	$\frac{300 k\Omega}{R_{in}}$	$\frac{360 k\Omega}{R_{in}}$	V/V
R_{STDBY}	Internal Resistance From Standby to GND	240	300	360	$k\Omega$
F_{PWM}	Pulse Width Modulator Base Frequency		250		kHz
SNR	Signal to Noise ratio (A Weighting), $P_o = 0.4W$, $R_L = 8\Omega$		82		dB
T_{WU}	Wake-up time		5		ms
T_{STB}	Standby time		5		ms
V_N	Output Voltage Noise $f = 20Hz$ to $20kHz$, $G = 6dB$ Unweighted $R_L = 4\Omega$ A weighted $R_L = 4\Omega$ Unweighted $R_L = 8\Omega$ A weighted $R_L = 8\Omega$ Unweighted $R_L = 4\Omega + 15\mu H$ A weighted $R_L = 4\Omega + 15\mu H$ Unweighted $R_L = 4\Omega + 30\mu H$ A weighted $R_L = 4\Omega + 30\mu H$ Unweighted $R_L = 8\Omega + 30\mu H$ A weighted $R_L = 8\Omega + 30\mu H$ Unweighted $R_L = 4\Omega + Filter$ A weighted $R_L = 4\Omega + Filter$ Unweighted $R_L = 4\Omega + Filter$ A weighted $R_L = 4\Omega + Filter$		83 57 83 61 81 58 87 62 77 56 85 63 80 57 85 61		μV_{RMS}

1) All electrical values are guaranteed with correlation measurements at 2.5V and 5V.

2) Standby mode is activated when V_{stdby} is tied to GND.

3) Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. V_{ripple} is the surimposed sinus signal to V_{cc} @ $f = 217Hz$.

Table 7: $V_{CC} = +2.5V$, $GND = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
I_{CC}	Supply Current No input signal, no load		1.7		mA
$I_{STANDBY}$	Standby Current ¹ No input signal, $V_{STBY} = GND$		10	1000	nA
V_{OO}	Output Offset Voltage No input signal, $R_L = 8\Omega$		3		mV
P_o	Output Power, $G=6dB$ THD = 2% Max, $f = 1kHz$, $R_L = 4\Omega$ THD = 1% Max, $f = 1kHz$, $R_L = 8\Omega$		0.45 0.3		W
THD + N	Total Harmonic Distortion + Noise $P_o = 200\text{ mW}_{RMS}$, $G = 6dB$, $20Hz < f < 20kHz$, $R_L = 8\Omega + 15\mu H$, $BW < 30kHz$		1		%
Efficiency	Efficiency $P_o = 0.45\text{ W}_{RMS}$, $R_L = 4\Omega + \geq 15\mu H$ $P_o = 0.3\text{ W}_{RMS}$, $R_L = 8\Omega + \geq 15\mu H$		78 87		%
PSRR	Power Supply Rejection Ratio with inputs grounded ² $f = 217Hz$, $R_L = 8\Omega$, $G=6dB$, $V_{ripple} = 200mV_{pp}$		60		dB
CMRR	Common Mode Rejection Ratio, $f = 217Hz$, $R_L = 8\Omega$, $G = 6dB$, $\Delta V_{ic} = 200mV_{pp}$		54		dB
Gain	Gain value (R_{in} in $k\Omega$)	$\frac{240\text{ k}\Omega}{R_{in}}$	$\frac{300\text{ k}\Omega}{R_{in}}$	$\frac{360\text{ k}\Omega}{R_{in}}$	V/V
R_{STDBY}	Internal Resistance From Standby to GND	240	300	360	$k\Omega$
F_{PWM}	Pulse Width Modulator Base Frequency		250		kHz
SNR	Signal to Noise ratio (A Weighting), $P_o = 0.4W$, $R_L = 8\Omega$		80		dB
T_{WU}	Wake-up time		5		ms
T_{STB}	Standby time		5		ms
V_N	Output Voltage Noise $f = 20Hz$ to $20kHz$, $G = 6dB$ Unweighted $R_L = 4\Omega$ A weighted $R_L = 4\Omega$ Unweighted $R_L = 8\Omega$ A weighted $R_L = 8\Omega$ Unweighted $R_L = 4\Omega + 15\mu H$ A weighted $R_L = 4\Omega + 15\mu H$ Unweighted $R_L = 4\Omega + 30\mu H$ A weighted $R_L = 4\Omega + 30\mu H$ Unweighted $R_L = 8\Omega + 30\mu H$ A weighted $R_L = 8\Omega + 30\mu H$ Unweighted $R_L = 4\Omega + \text{Filter}$ A weighted $R_L = 4\Omega + \text{Filter}$ Unweighted $R_L = 4\Omega + \text{Filter}$ A weighted $R_L = 4\Omega + \text{Filter}$		85 60 86 62 76 56 82 60 67 53 78 57 74 54 78 59		μV_{RMS}

1) Standby mode is activated when V_{stdby} is tied to GND.

2) Dynamic measurements - $20 \cdot \log(\text{rms}(V_{out})/\text{rms}(V_{ripple}))$. Vripple is the surimposed sinus signal to V_{cc} @ $f = 217Hz$.

**Tip:**

In the graphs that follow, the abbreviations are used:

R_L + nothing = pure resistive load

Filter = LC output filter ($1\mu\text{F}+30\mu\text{H}$ for 4Ω and $0.5\mu\text{F}+60\mu\text{H}$ for 8Ω)

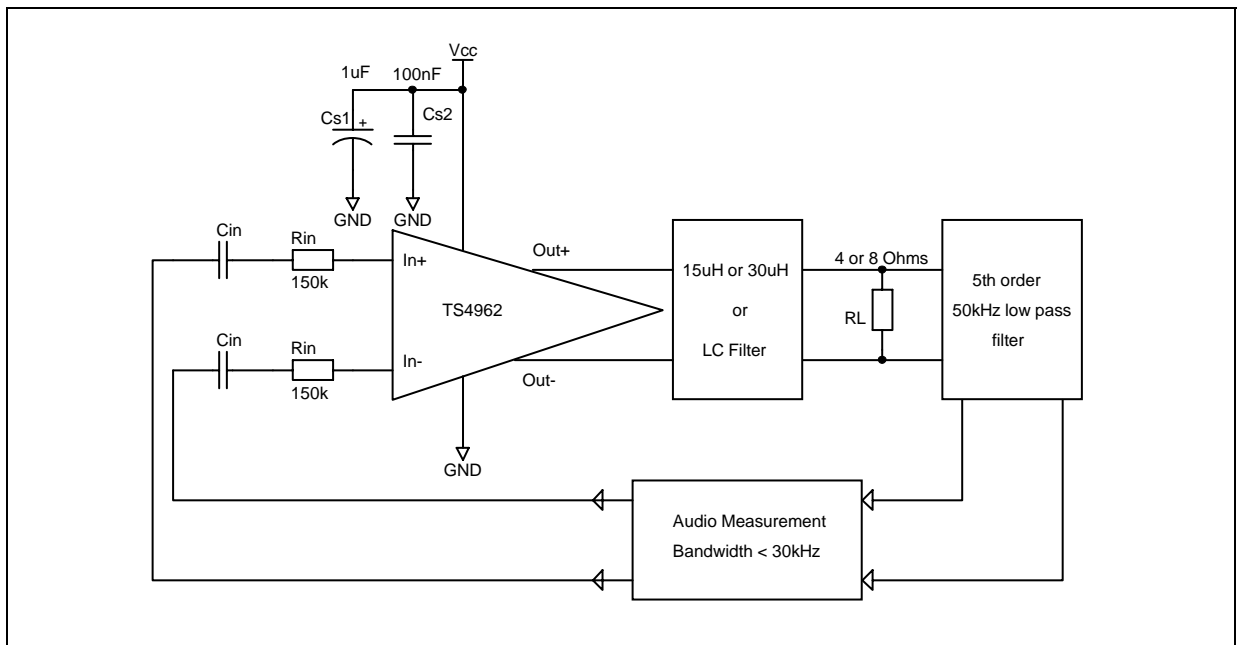
Figure 2: Test diagram for measurements

Figure 3: Current consumption vs power supply voltage

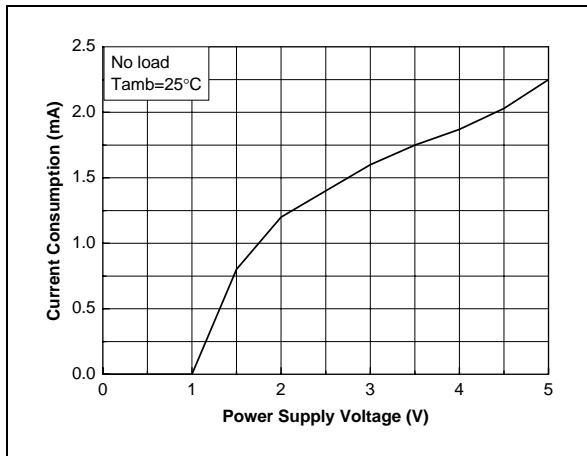


Figure 4: Current consumption vs standby voltage

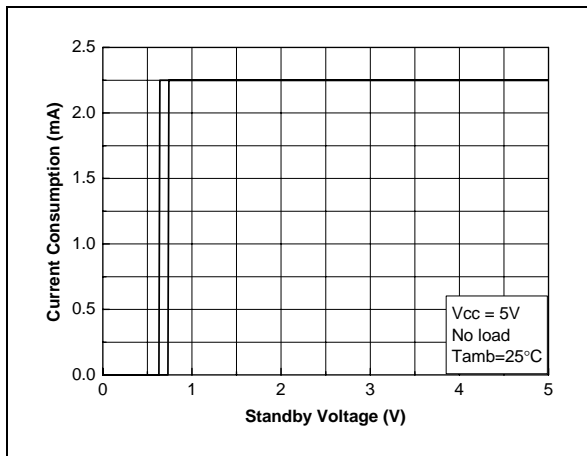


Figure 5: Current consumption vs standby voltage

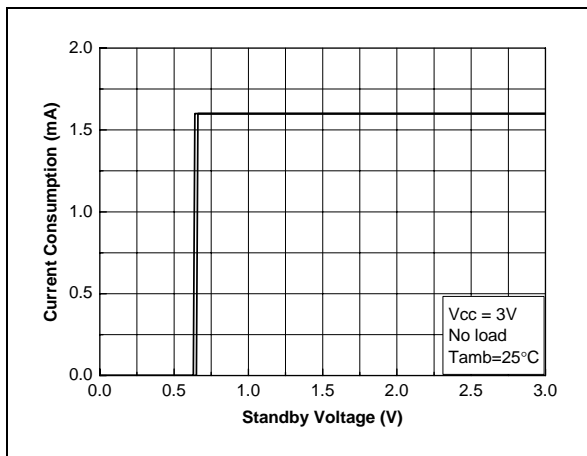


Figure 6: Output offset voltage vs common mode input voltage

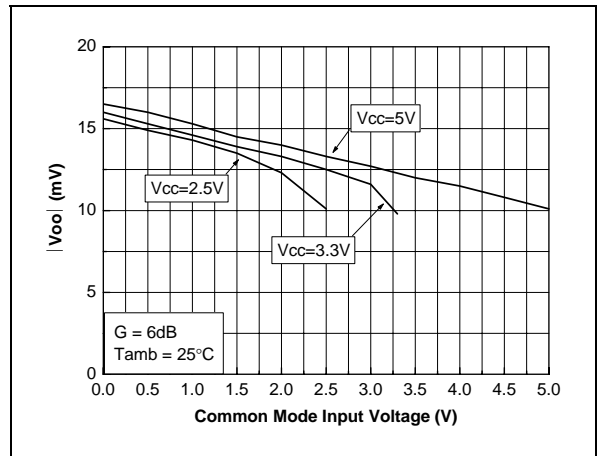


Figure 7: Efficiency vs output power

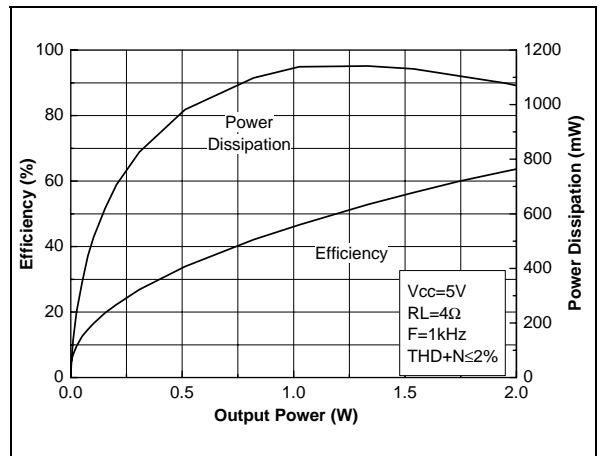


Figure 8: Efficiency vs output power

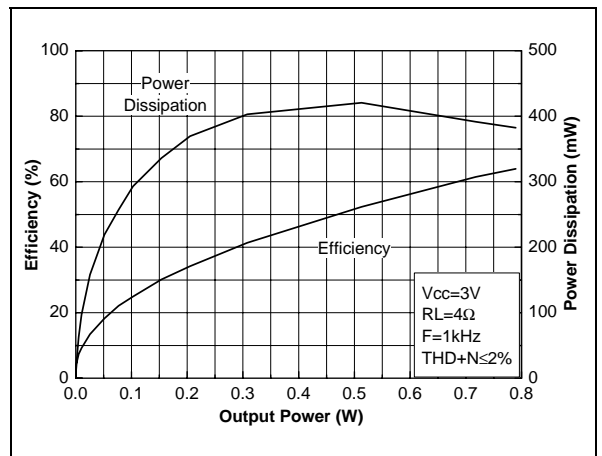


Figure 9: Efficiency vs output power

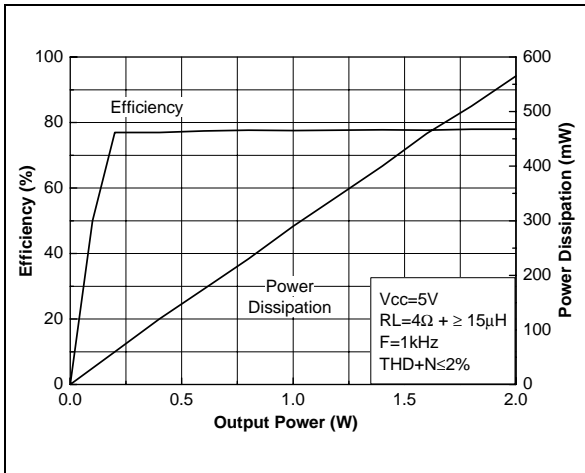


Figure 10: Efficiency vs output power

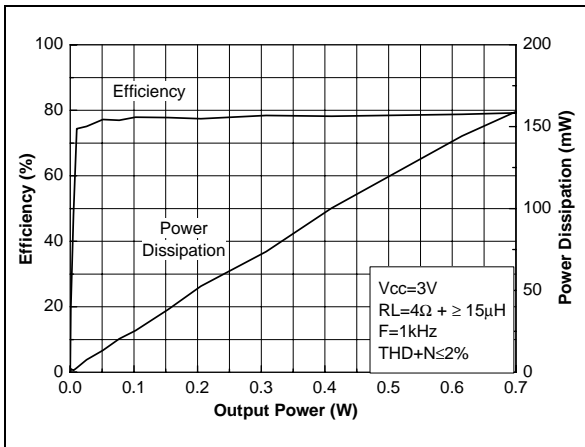


Figure 11: Efficiency vs output power

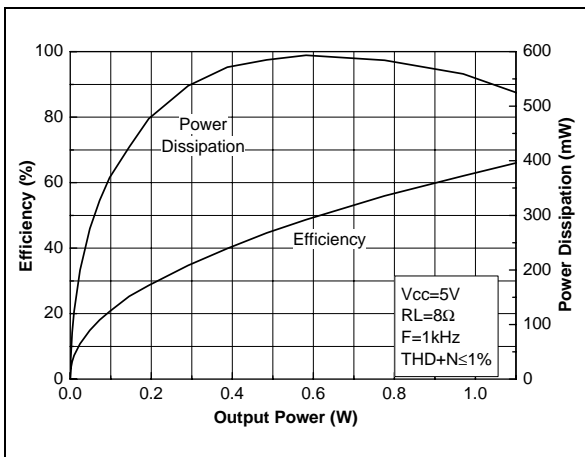


Figure 12: Efficiency vs output power

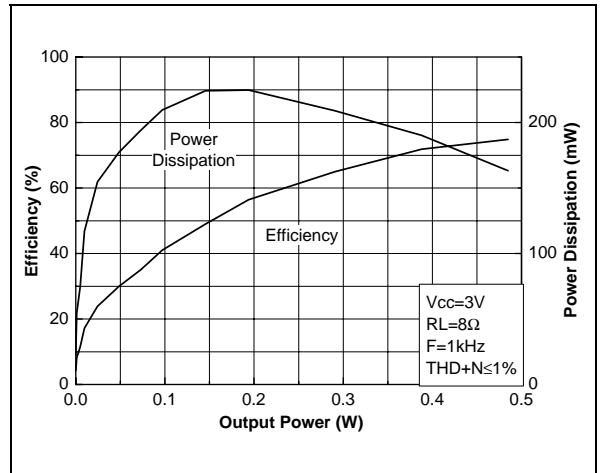


Figure 13: Efficiency vs output power

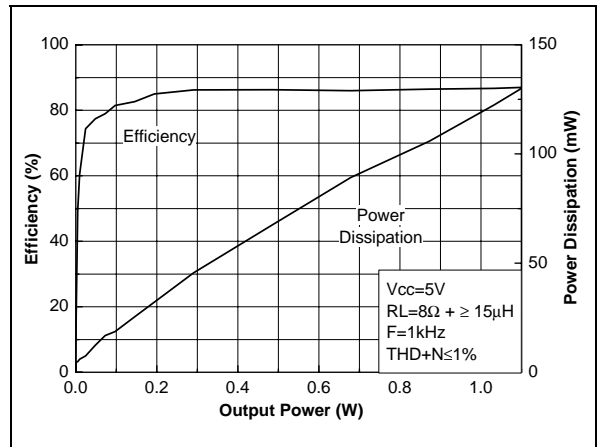


Figure 14: Efficiency vs output power

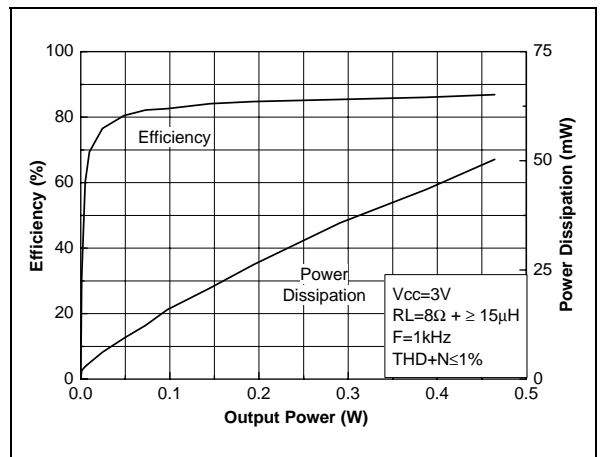


Figure 15: Output power vs power supply voltage

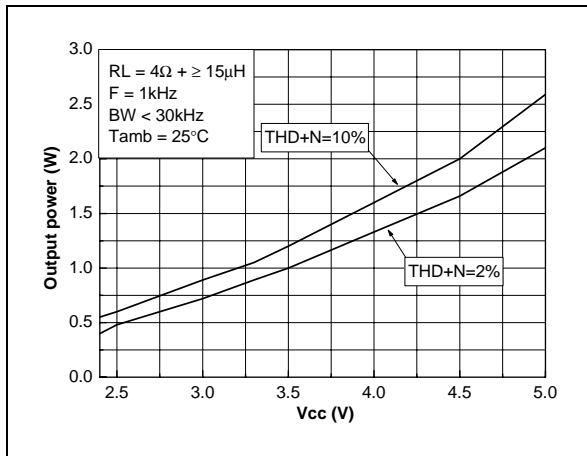


Figure 16: Output power vs power supply voltage

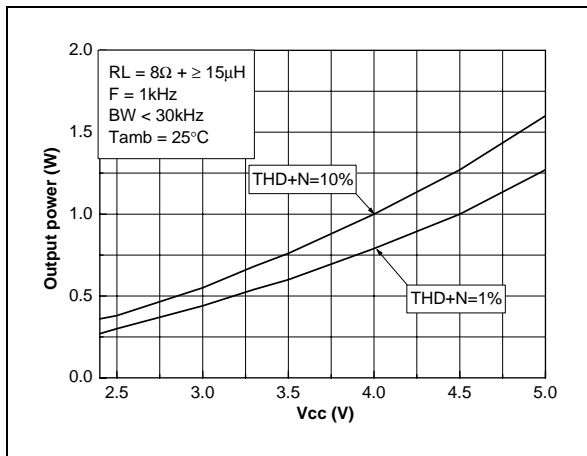


Figure 17: PSRR vs frequency

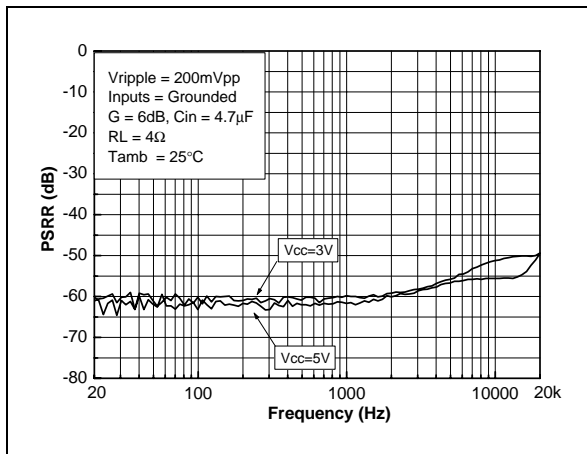


Figure 18: PSRR vs frequency

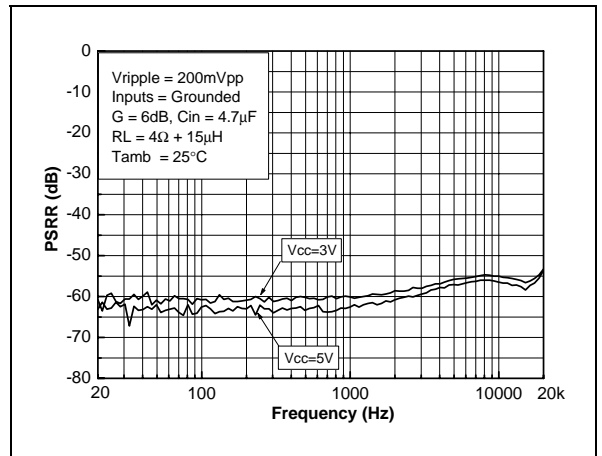


Figure 19: PSRR vs frequency

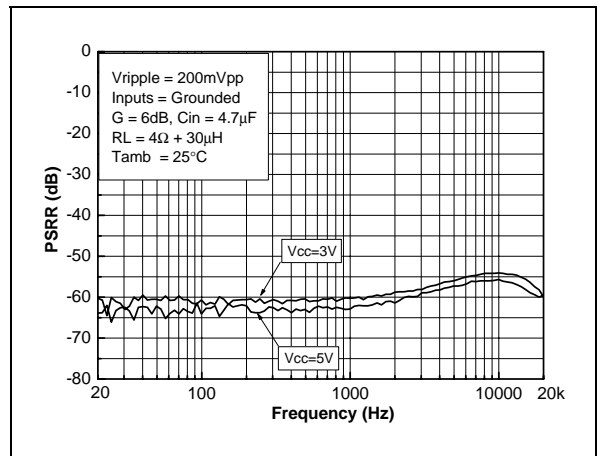


Figure 20: PSRR vs frequency

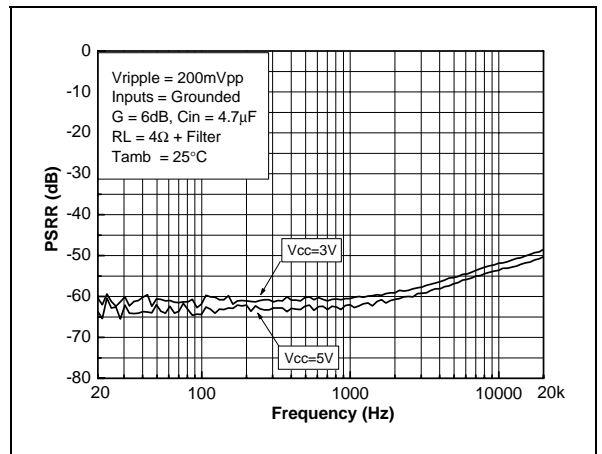


Figure 21: Output power vs power supply voltage

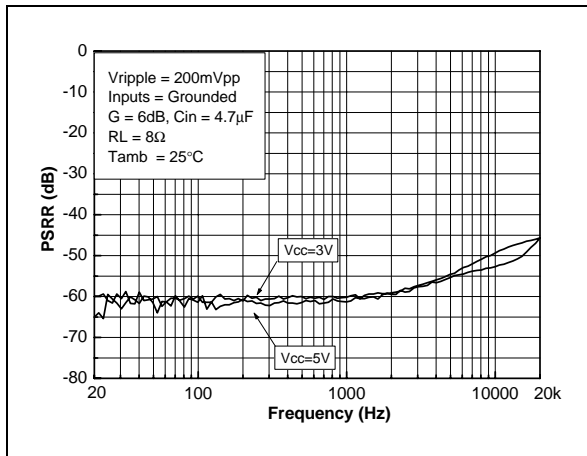


Figure 22: Output power vs power supply voltage

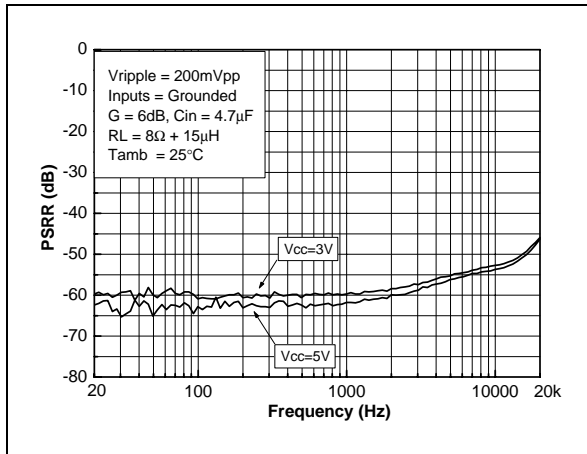


Figure 23: PSRR vs frequency

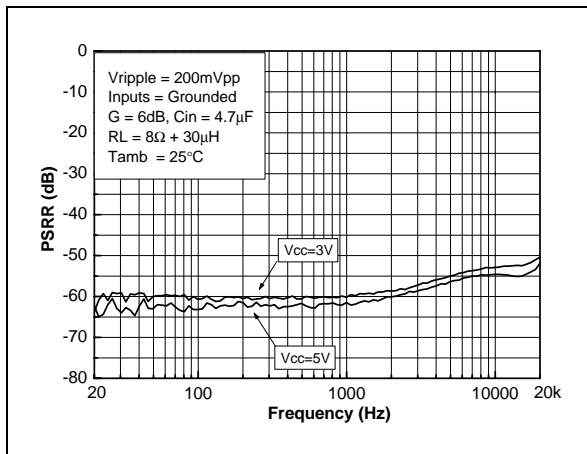


Figure 24: PSRR vs frequency

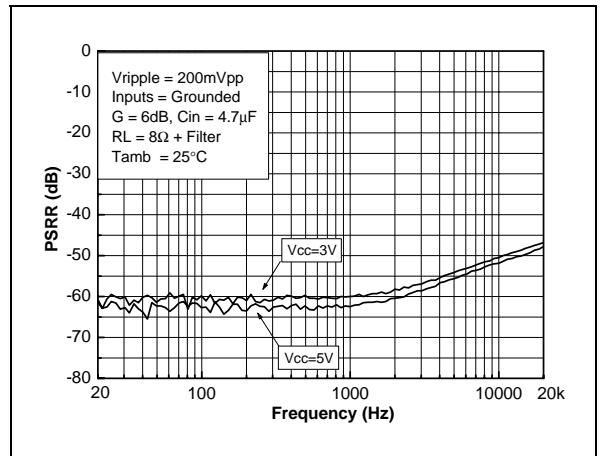


Figure 25: PSRR vs frequency Common Mode Input Voltage

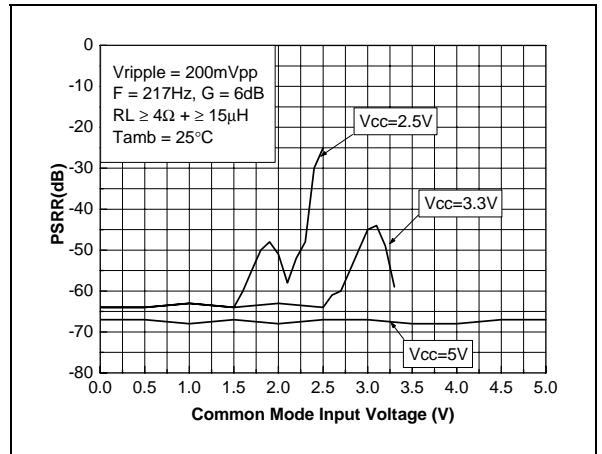


Figure 26: CMRR vs frequency

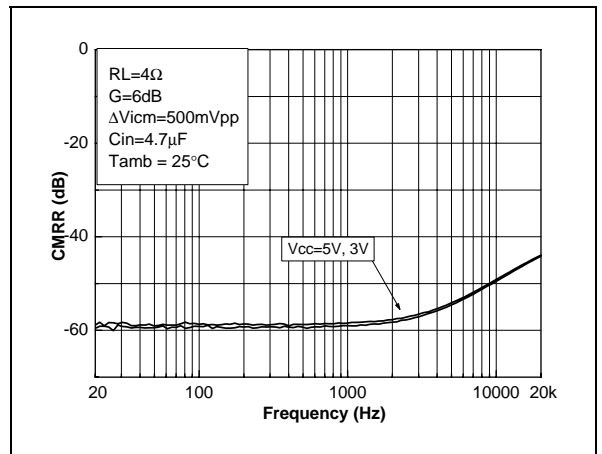


Figure 27: CMRR vs frequency

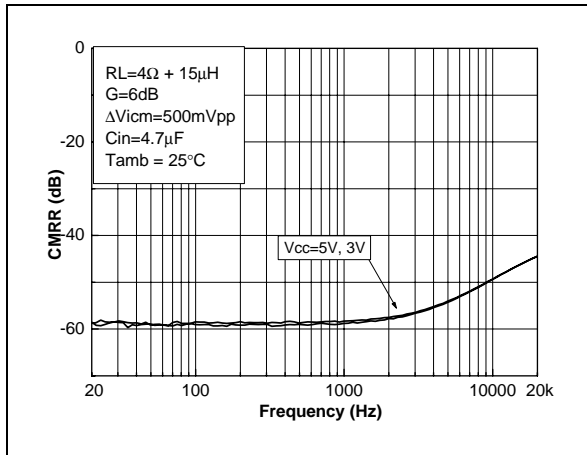


Figure 30: CMRR vs frequency

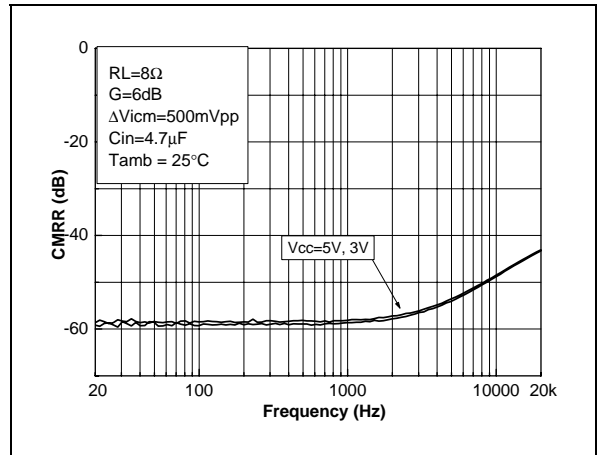


Figure 28: CMRR vs frequency

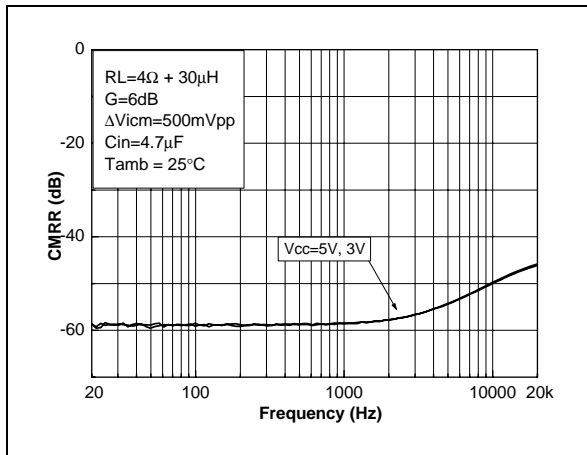


Figure 31: CMRR vs frequency

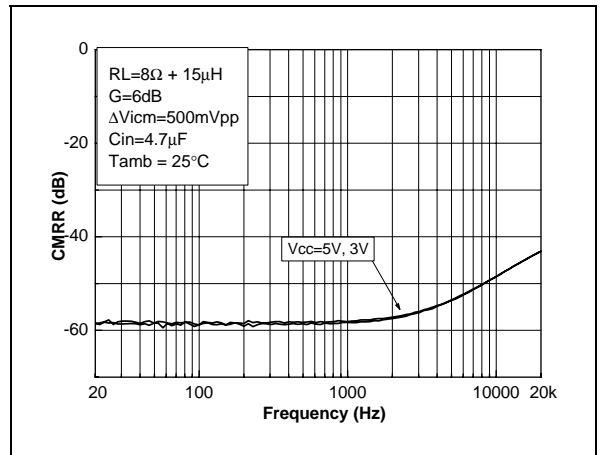


Figure 29: CMRR vs frequency

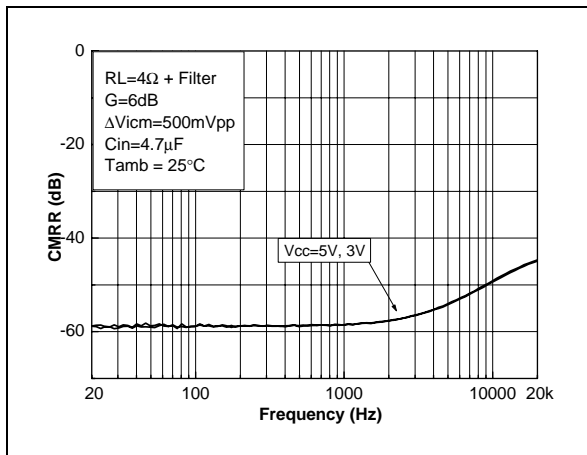


Figure 32: CMRR vs frequency

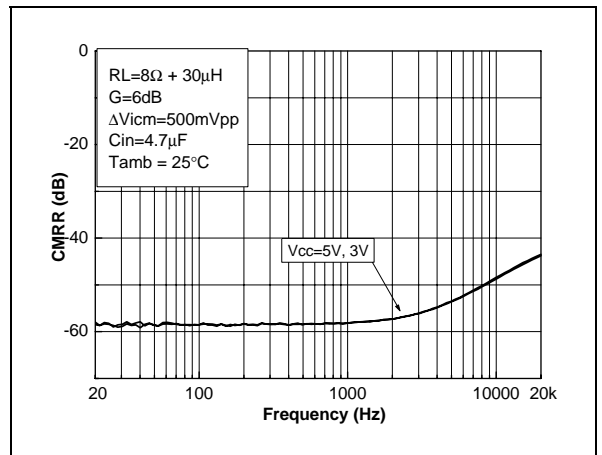


Figure 33: CMRR vs frequency

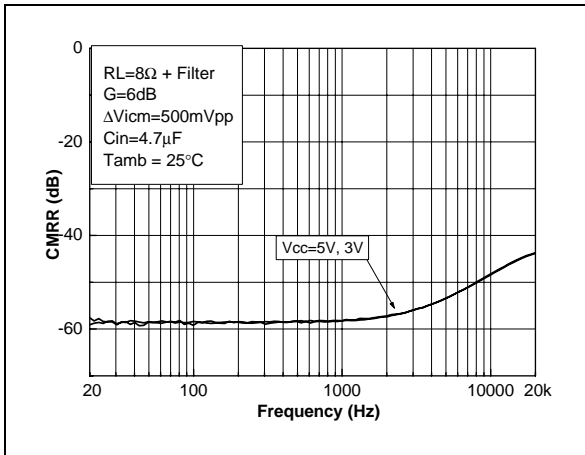


Figure 34: PSRR vs frequency common mode input voltage

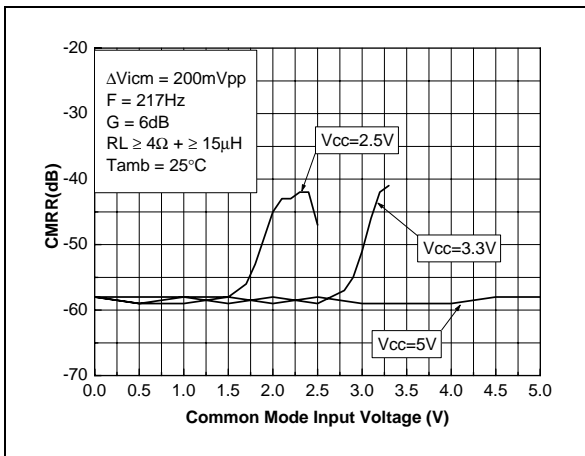


Figure 35: THD+N vs output power

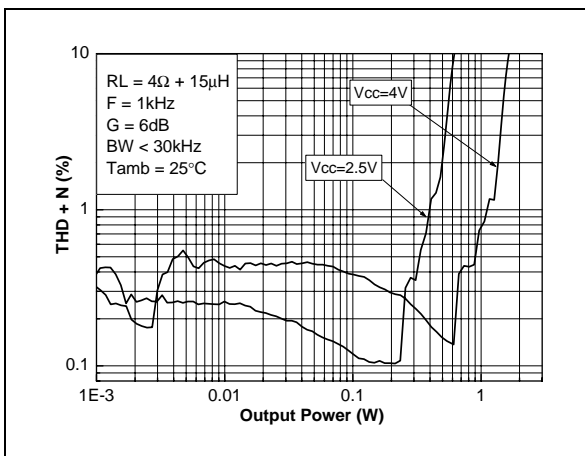


Figure 36: THD+N vs output power

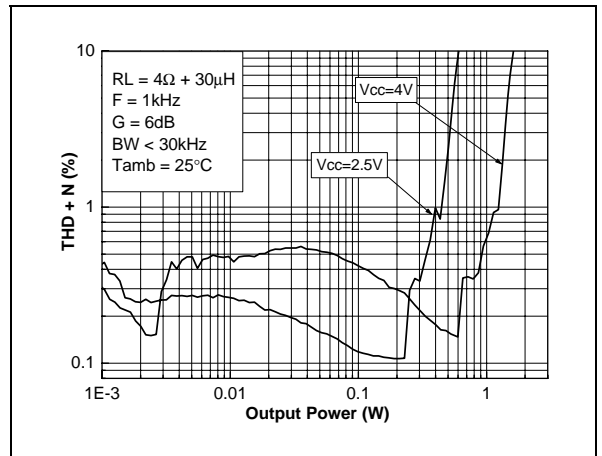


Figure 37: THD+N vs output power

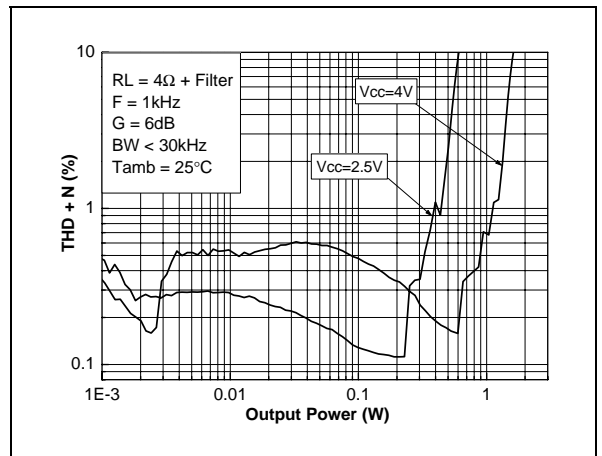


Figure 38: THD+N vs output power

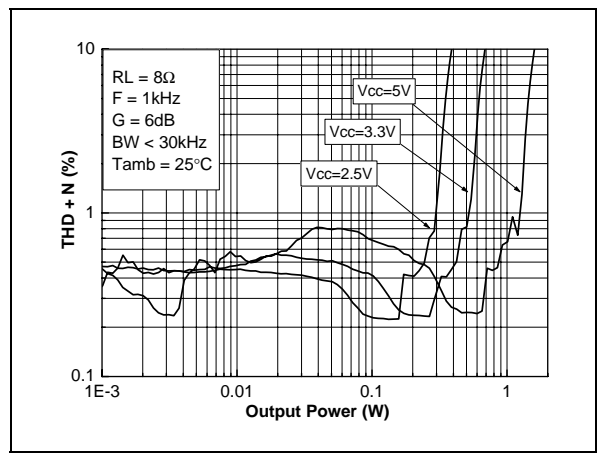


Figure 39: THD+N vs output power

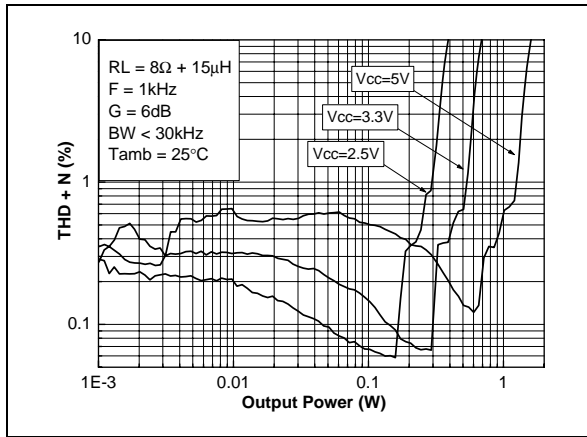


Figure 42: THD+N vs frequency

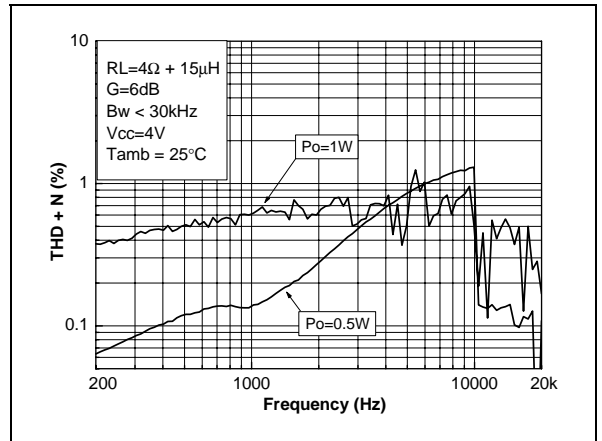


Figure 40: THD+N vs output power

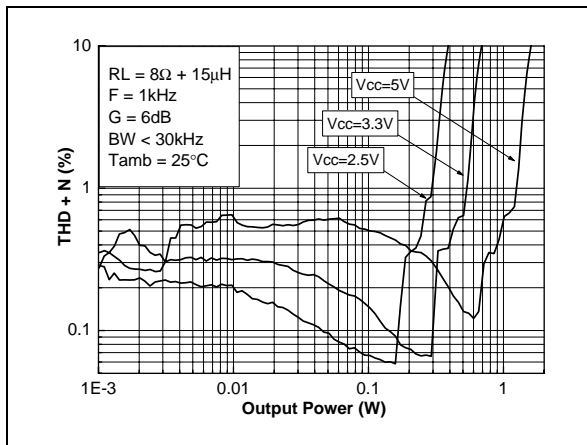


Figure 43: THD+N vs frequency

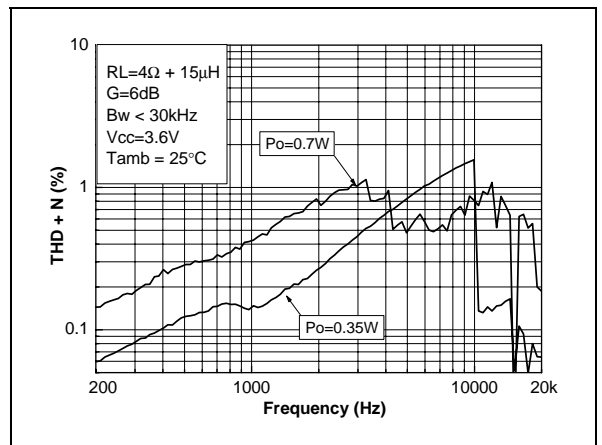


Figure 41: THD+N vs output power

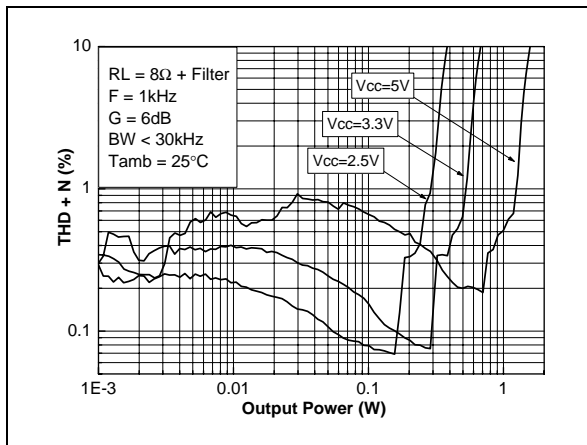


Figure 44: THD+N vs frequency

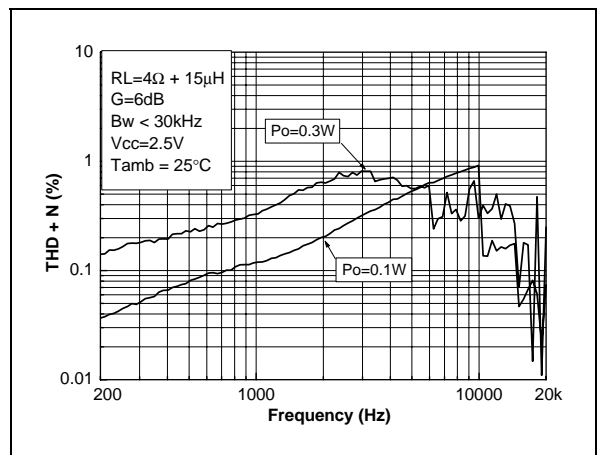


Figure 45: THD+N vs frequency

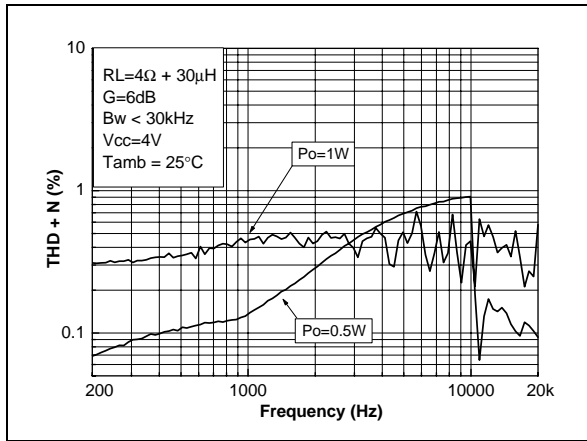


Figure 48: THD+N vs frequency

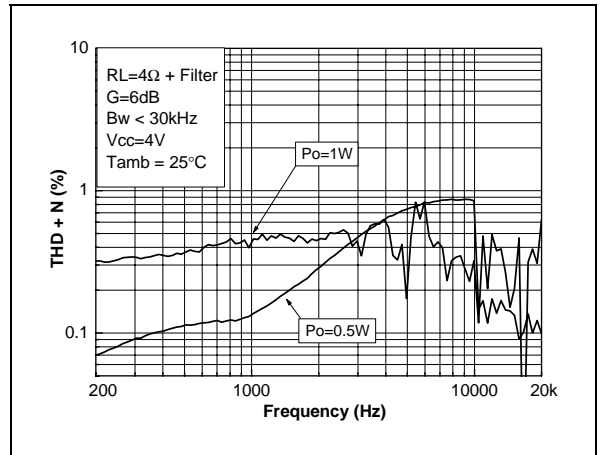


Figure 46: THD+N vs frequency

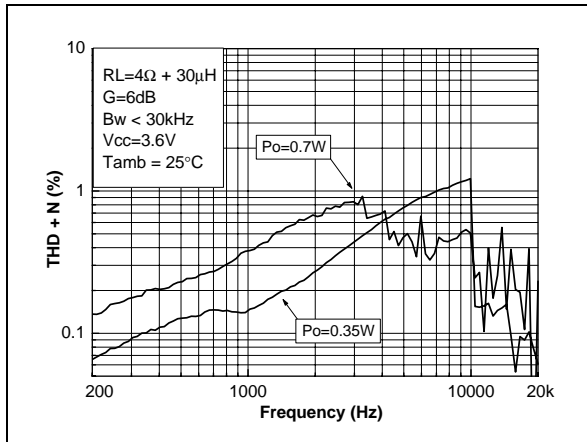


Figure 49: THD+N vs frequency

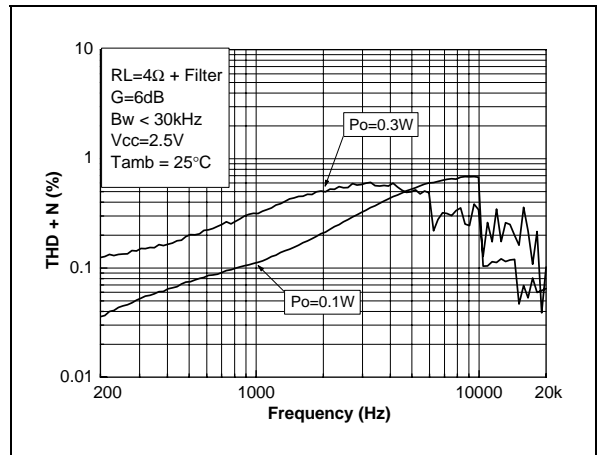


Figure 47: THD+N vs frequency

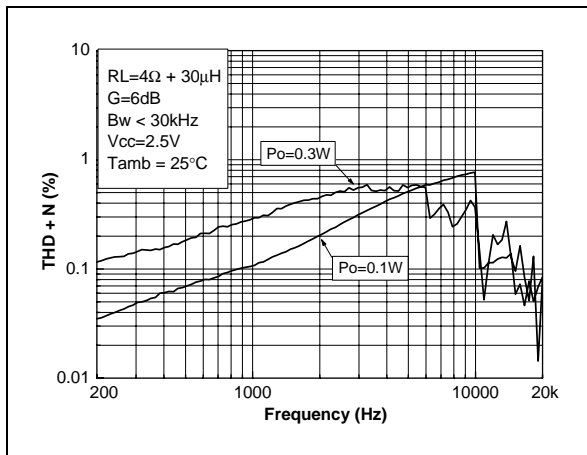


Figure 50: THD+N vs frequency

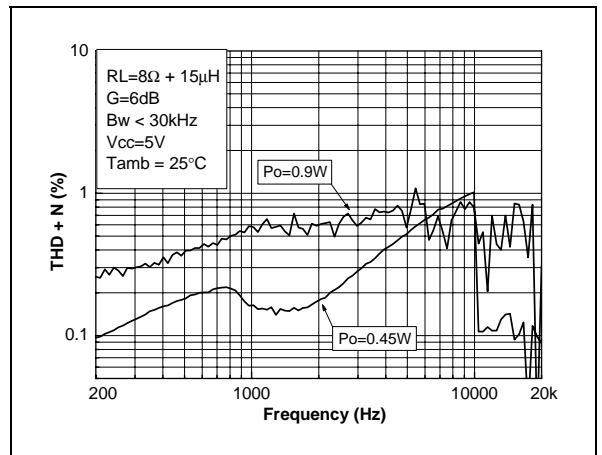


Figure 51: THD+N vs frequency

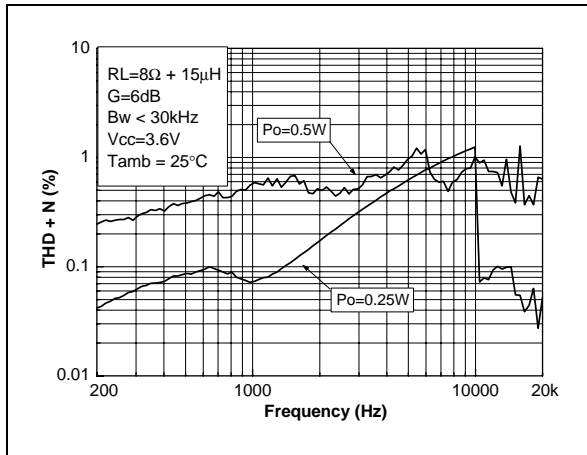


Figure 54: THD+N vs frequency

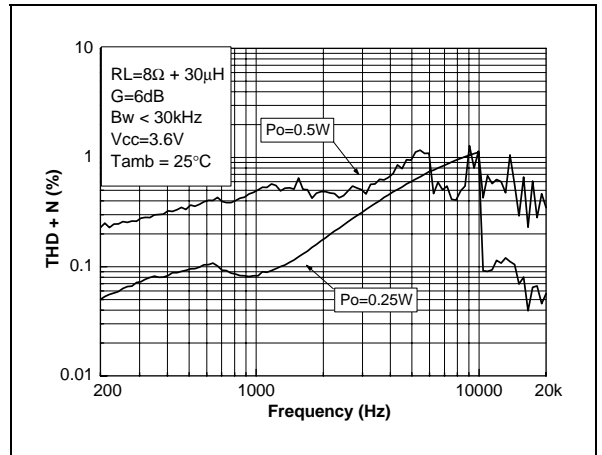


Figure 52: THD+N vs frequency

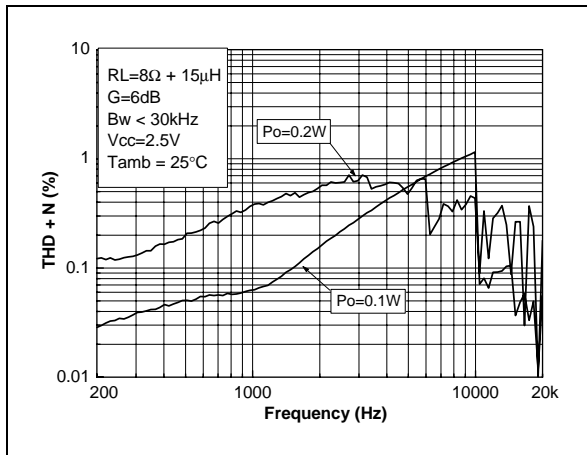


Figure 55: THD+N vs frequency

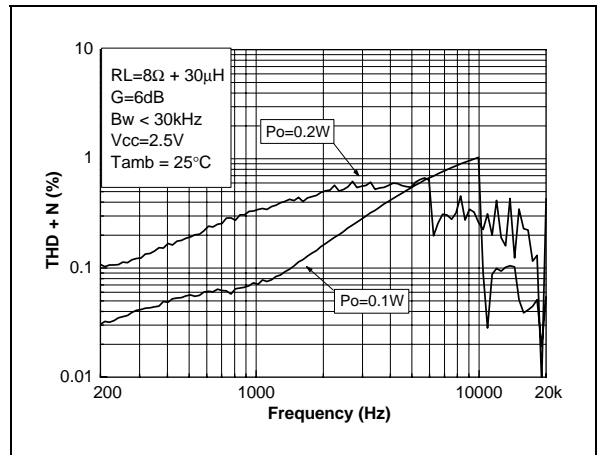


Figure 53: THD+N vs frequency

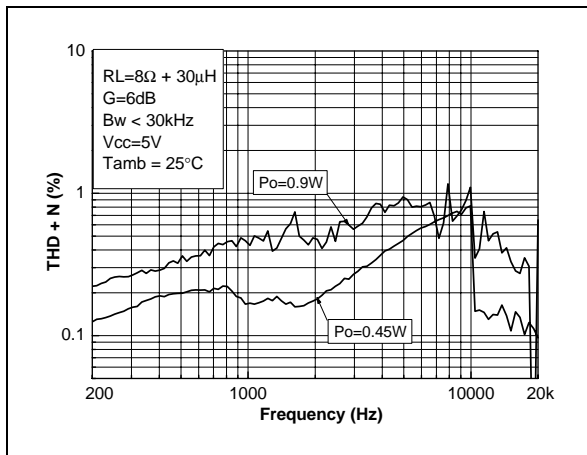


Figure 56: THD+N vs frequency

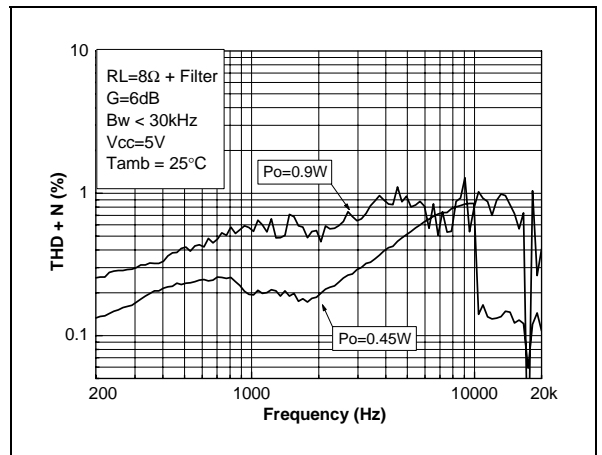


Figure 57: THD+N vs frequency

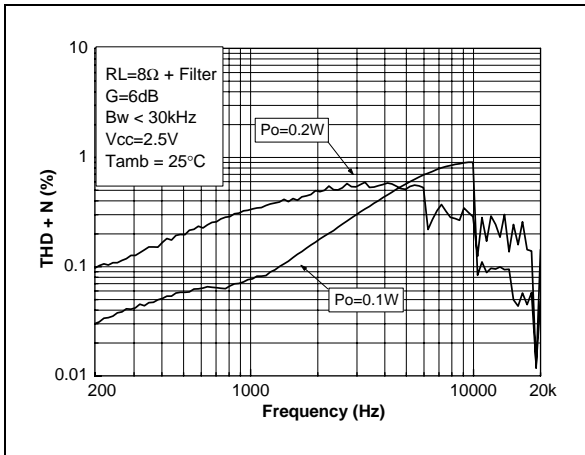


Figure 60: Gain vs frequency

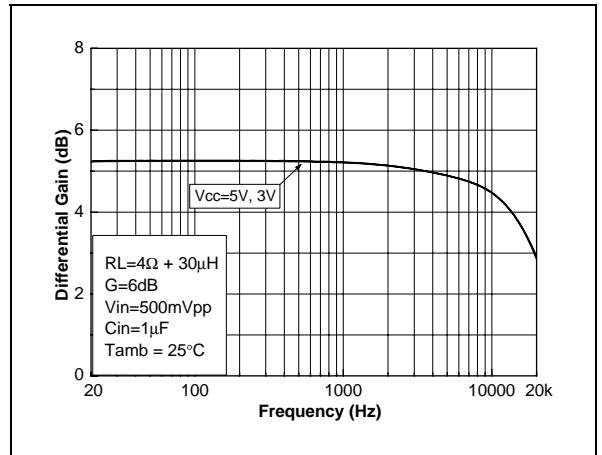


Figure 58: Gain vs frequency

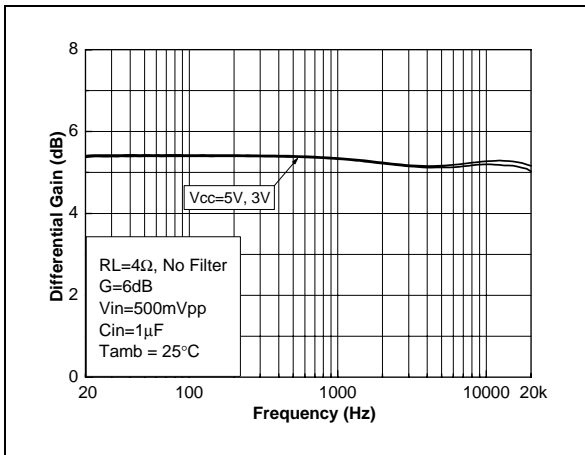


Figure 61: Gain vs frequency

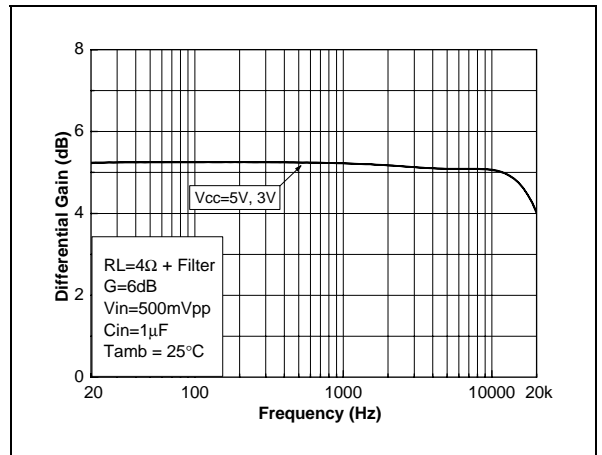


Figure 59: Gain vs frequency

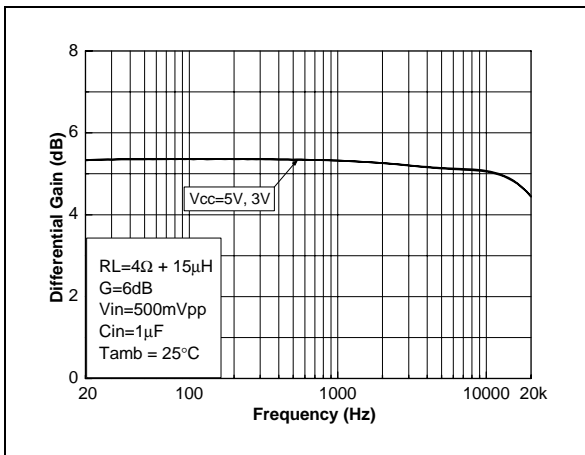


Figure 62: Gain vs frequency

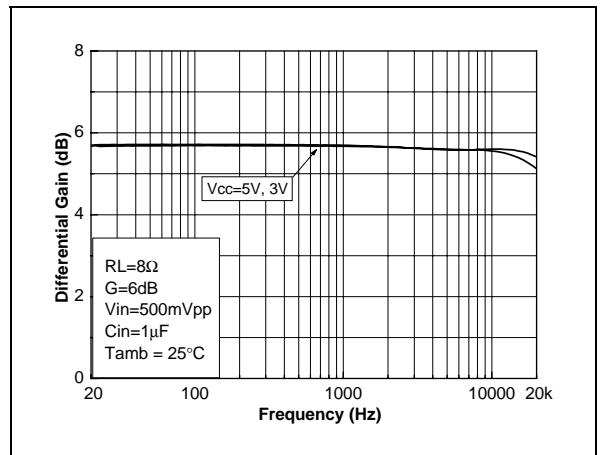


Figure 63: Gain vs frequency

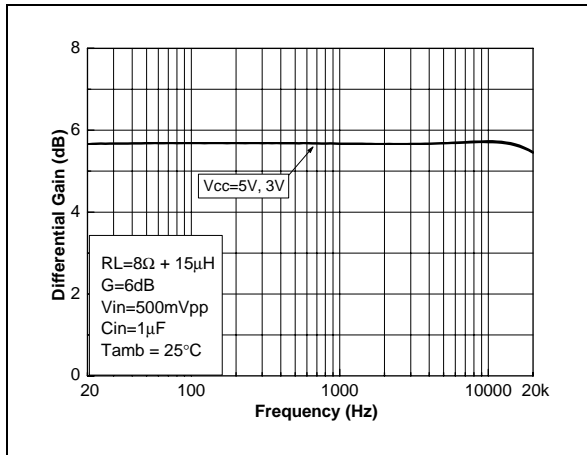


Figure 66: Gain vs frequency

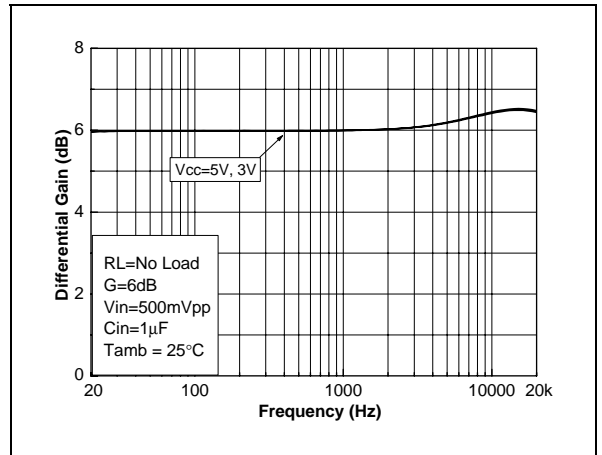


Figure 64: Gain vs frequency

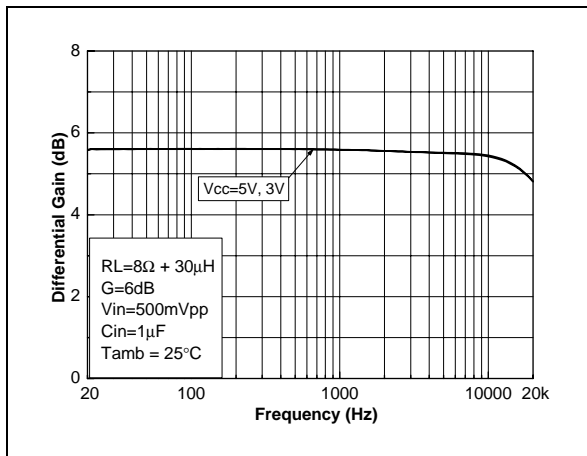


Figure 67: Startup & shutdown time
 $V_{CC}=5V, G=6dB, C_{IN}=1\mu F$ (5ms/div)

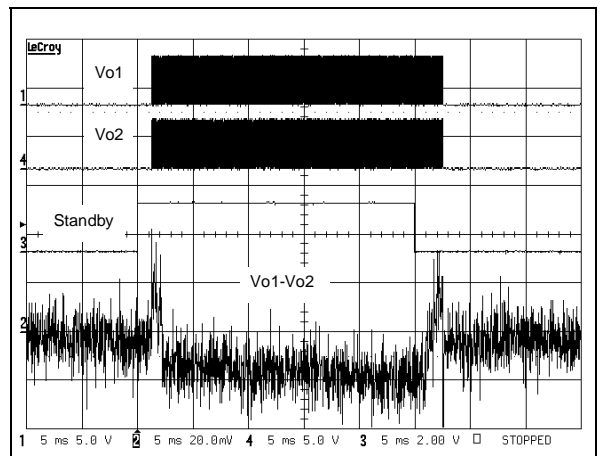


Figure 65: Gain vs frequency

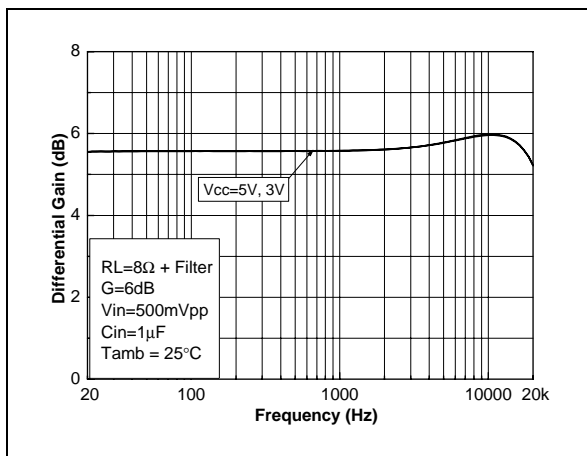


Figure 68: Startup & shutdown time
 $V_{CC}=3V, G=6dB, C_{IN}=1\mu F$ (5ms/div)

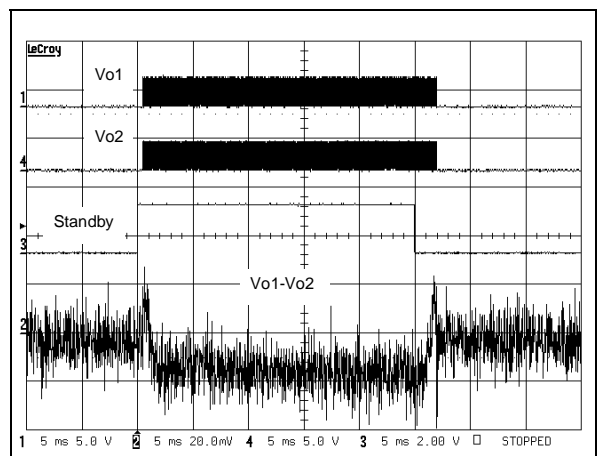


Figure 69: Startup & shutdown time
 $V_{CC}=5V$, $G=6dB$, $C_{IN}=100nF$ (5ms/div)

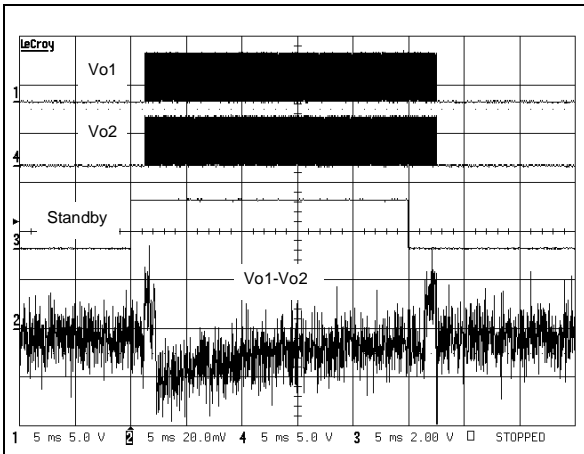


Figure 72: Startup & shutdown time
 $V_{CC}=3V$, $G=6dB$, NoC_{IN} (5ms/div)

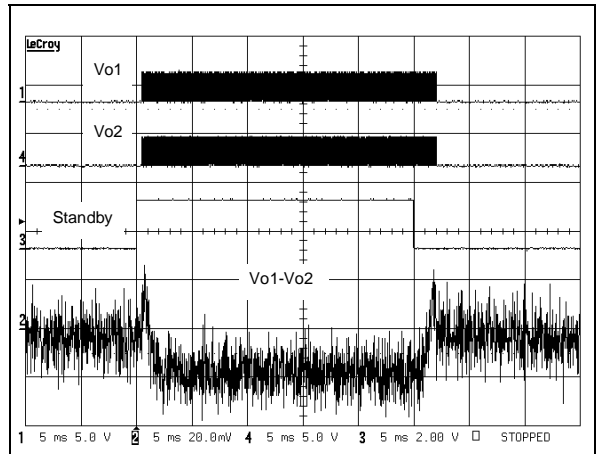


Figure 70: Startup & shutdown time
 $V_{CC}=3V$, $G=6dB$, $C_{IN}=100nF$ (5ms/div)

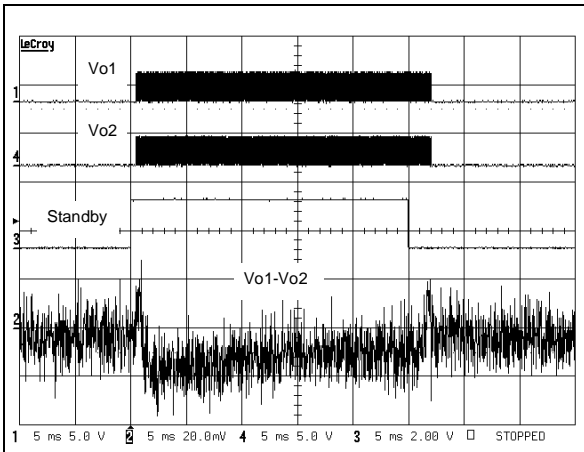
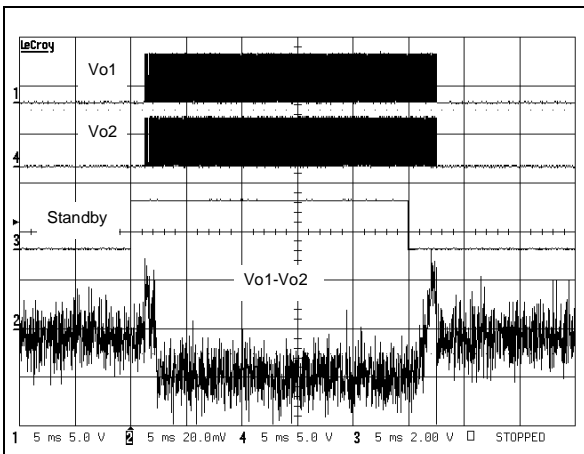


Figure 71: Startup & shutdown time
 $V_{CC}=5V$, $G=6dB$, NoC_{IN} (5ms/div)



4 Package Mechanical Data

4.1 9 CONNECTIONS - Flip-Chip 300 μ m bump diam.

Figure 73: Pin out (top view)

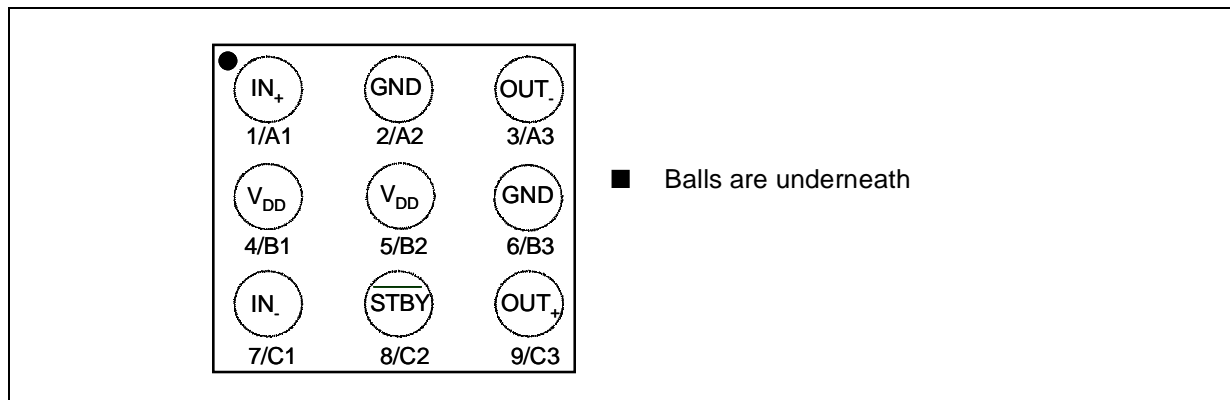
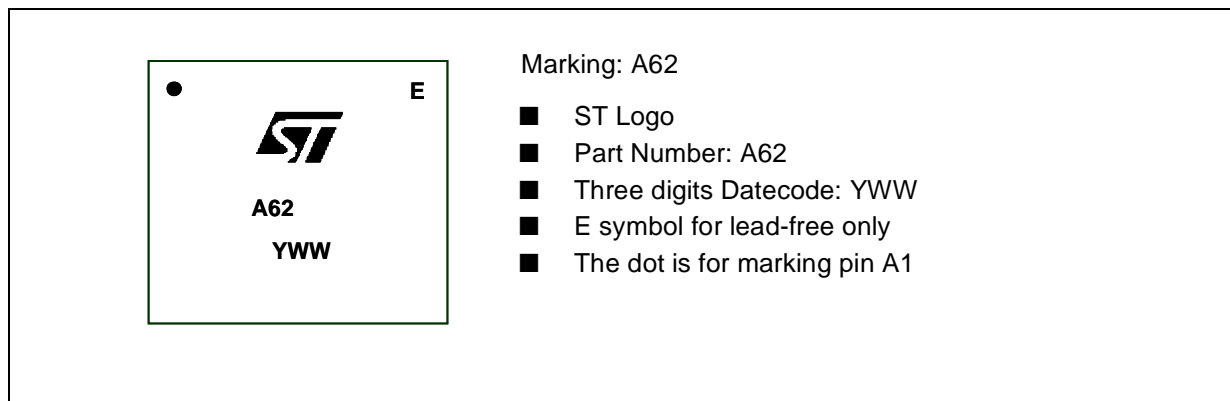
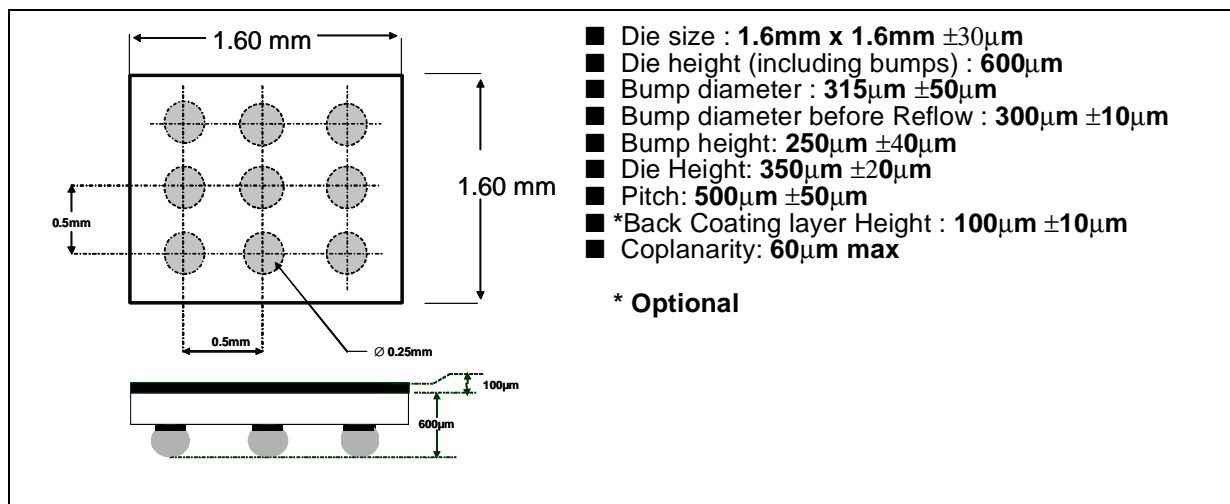


Figure 74: Marking (top view)



4.2 FLIP CHIP - 9 BUMPS



5 Revision History

Date	Revision	Description of Changes
01 Nov 2004	1	First Release

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